

DTQ6334 www.din-tek.jp

RoHS COMPLIANT

# N-Channel 30 V (D-S) MOSFET

Top View

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PRODUCT SUMMARY						
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A) <sup>a, e</sup>	Q <sub>g</sub> (Typ.)			
30	0.0025 at V <sub>GS</sub> = 10 V	95	42 nC			
30	0.0046 at V <sub>GS</sub> = 4.5 V	70	42 110			

#### **FEATURES**

- DT-Trench Power MOSFET
- 100 % R<sub>g</sub> and UIS Tested

#### **APPLICATIONS**

- OR-ing
- Server ٠

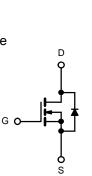
8 D

7 D

6 D

5 D

Notebook PC Core •



DFN5X6 Top View **Bottom View** PIN1

#### N-Channel MOSFET

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	30	V		
Gate-Source Voltage		V <sub>GS</sub>	± 20	v	
	T <sub>C</sub> = 25 °C		95 <sup>a, e</sup>		
Continuous Drain Current (T <sub>J</sub> = 175 °C)	T <sub>C</sub> = 70 °C	I <sub>D</sub>	80 <sup>e</sup>		
Continuous Drain Ourient (1) = 175 (C)	T <sub>A</sub> = 25 °C	טי	30 <sup>b, c</sup>	Α	
	T <sub>A</sub> = 70 °C		21 <sup>b, c</sup>	~ ~	
Pulsed Drain Current	I <sub>DM</sub>	360			
Avalanche Current Pulse	L = 0.1 mH	I <sub>AS</sub>	86		
Single Pulse Avalanche Energy	L = 0.1 mm	E <sub>AS</sub>	59	mJ	
Continuous Source-Drain Diode Current	T <sub>C</sub> = 25 °C	I <sub>S</sub>	95 <sup>a, e</sup>	Α	
Continuous Source-Drain Diode Current	T <sub>A</sub> = 25 °C	18	3.1 <sup>b, c</sup>		
	T <sub>C</sub> = 25 °C		240 <sup>a</sup>		
Maximum Power Dissinction	T <sub>C</sub> = 70 °C	PD	155	w	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C		3.62 <sup>b, c</sup>	vv	
	T <sub>A</sub> = 70 °C		2.43 <sup>b, c</sup>		
Operating Junction and Storage Temperature R	ange	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient <sup>b, d</sup>	$t \le 10 \text{ s}$	R <sub>thJA</sub>	35	40	°C/W		
Maximum Junction-to-Case	Steady State	R <sub>thJC</sub>	0.5	0.8	C/W		

Notes:

a. Based on  $T_C = 25 \text{ °C}$ . b. Surface mounted on 1" x 1" FR4 board.

c. t = 10 s.

d. Maximum under steady state conditions is 90 °C/W.

e. Calculated based on maximum junction temperature. Package limitation current is 95 A.

Parameter	Symbol	Test Conditions	Min .	Тур.	Max.	Unit
Static				•		
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = 250 \mu A$	30			V
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{J}$	$\Delta V_{DS}/T_J$ $I_D = 250 \mu A$		35		mV/°C
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	η – 200 μλ		- 7.5		mv/-C
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1		3	V
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
		$V_{DS} = 24 V, V_{GS} = 0 V$			1	μA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ = 24 V, $V_{GS}$ = 0 V, $T_{J}$ = 55 °C			10	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	120			А
	Р	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	0.0025		0.0030	~
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS}$ = 4.5 V, I <sub>D</sub> = 20 A		0.0046	0.0055	Ω
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 30 A		155		S
Dynamic <sup>b</sup>				•		
Input Capacitance	C <sub>iss</sub>			4765		
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ = 24 V, $V_{GS}$ = 0 V, f = 1 MHz		1025		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			570		
Total Gate Charge	Qg	$V_{DS} = 24$ V, $V_{GS} = 10$ V, $I_{D} = 30$ A		42		nC
				29		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = 24 V, $V_{GS}$ = 4.5 V, $I_D$ = 20 A		10		
Gate-Drain Charge	Q <sub>gd</sub>			14		
Gate Resistance	R <sub>g</sub>	f = 1 MHz		1.5	2.5	Ω
Turn-On Delay Time	t <sub>d(on)</sub>			23		ns
Rise Time	t <sub>r</sub>	$V_{DD}$ = 24 V, $R_L$ = 0.555 $\Omega$		11		
Turn-Off Delay Time	t <sub>d(off)</sub>	${\sf I}_{\sf D} \cong 30$ A, ${\sf V}_{\sf GEN}$ = 10 V, ${\sf R}_{\sf g}$ = 1 $\Omega$		60		
Fall Time	t <sub>f</sub>			13		
Turn-On Delay Time	t <sub>d(on)</sub>			50		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_L$ = 0.625 $\Omega$		166		
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}{\cong}24$ A, $\text{V}_\text{GEN}$ = 4.5 V, $\text{R}_\text{g}$ = 1 $\Omega$		47		
Fall Time	t <sub>f</sub>			11		
Drain-Source Body Diode Characteristic	s					
Continuous Source-Drain Diode Current	۱ <sub>S</sub>	$T_{C} = 25 \ ^{\circ}C$			95	A
Pulse Diode Forward Current <sup>a</sup>	I <sub>SM</sub>				360	
Body Diode Voltage	V <sub>SD</sub>	I <sub>S</sub> = 22 A		0.7	1.2	V
Body Diode Reverse Recovery Time	t <sub>rr</sub>			50	82	ns
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> = 20 A, di/dt = 100 A/μs, Τ <sub>J</sub> = 25 °C		70	98	nC
Reverse Recovery Fall Time	t <sub>a</sub>	$r_F = 20 \text{ A}, \text{ aval} = 100 \text{ Avps}, 1 \text{ J} = 25 ^{\circ}\text{C}$		20		
Reverse Recovery Rise Time	t <sub>b</sub>	t <sub>b</sub>		28		ns

Notes:

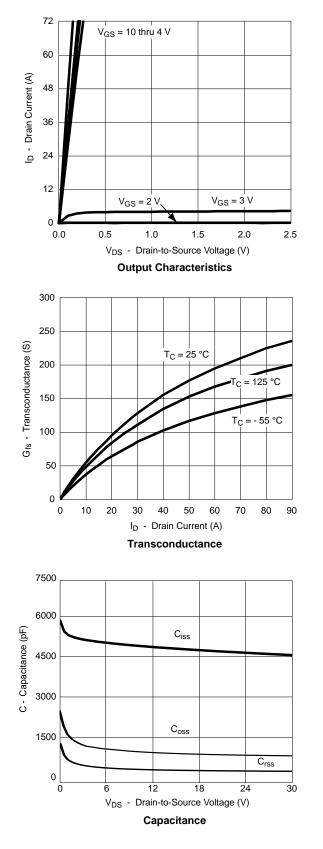
a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

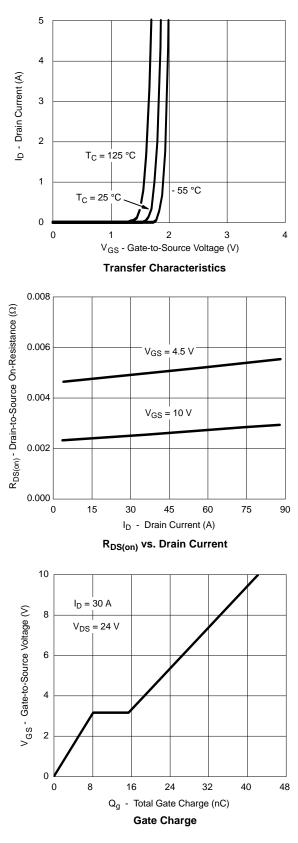
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

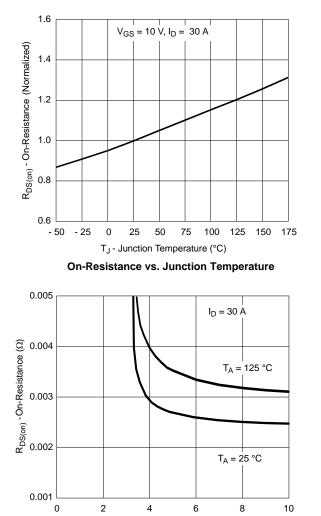


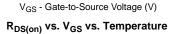


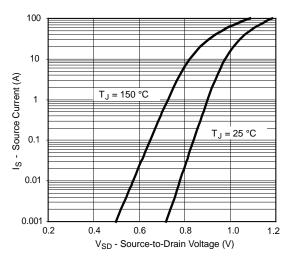


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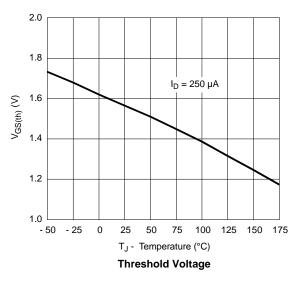
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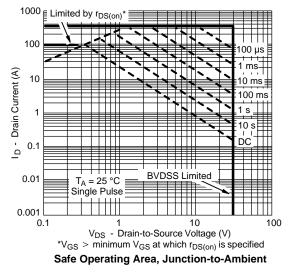






Forward Diode Voltage vs. Temperature

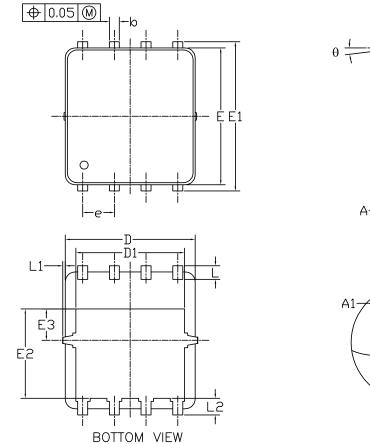




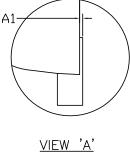
С

VIEW 'A'

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DFN5x6\_8L\_EP1\_P PACKAGE OUTLIN



(SCALE 5:1)

0.50 + - 4.60 - 0.55 0.50 + - 0.77 - 0.55 0.55 + - 0.635 + 0.635

+

+

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**RECOMMENDED LAND PATTERN** 

SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
STNBOLS	MIN	NOM	MAX	MIN	NOM	MAX
А	0.85	0.95	1.00	0.033	0.037	0.039
A1	0.00		0.05	0.000		0.002
b	0.30	0.40	0.50	0.012	0.016	0.020
с	0.15	0.20	0.25	0.006	0.008	0.010
D	4.80	5.20	5.30	0.201	0.205	0.209
D1	4.25	4.35	4.45	0.167	0.171	0.175
Е	5.45	5.55	5.65	0.215	0.219	0.222
E1	5.95	6.05	6.15	0.234	0.238	0.242
E2	3.525	3.625	3.725	0.139	0.143	0.147
E3	1.175	1.275	1.375	0.046	0.050	0.054
e	1.27 BSC			0.050 BSC		
L	0.45	0.55	0.65	0.018	0.022	0.026
L1	0		0.15	0		0.006
L2	0.68 REF			0.027 REF		
θ	0°		10°	0°		10°

NOTE

0.50-

6.15

UNIT: mm

0.65

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4.12

 PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS. MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 6 MILS EACH.
CONTROLLING DIMENSION IS MILLIMETER.

CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.



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